

# isc N-Channel MOSFET Transistor

**IRFSL4310** 

#### FEATURES

- Static drain-source on-resistance: R<sub>D</sub>s(on) ≤7.0mΩ
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

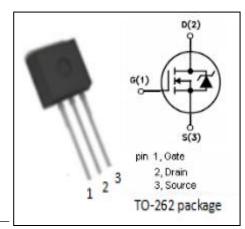
• reliable device for use in a wide variety of applications

## • ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	100	V
$V_{GS}$	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	130	А
I <sub>DM</sub>	Drain Current-Single Pulsed	550	А
P <sub>D</sub>	Total Dissipation @Tc=25℃	300	W
Tj	Max. Operating Junction Temperature	175	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~175	${\mathbb C}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.45	°C/W



13 Di H2	A2		E4
4	n	ım	
DIM	MIN	MAX	
A	4.37	4.77	
A1	1.22	1.42	
A2	2.47	2.87	
Ъ	0.70	0.97	
Ъ2	1.17	1.42	
С	0.28	0.53	
D	23.20	24.02	
D1	8.38	8.90	
D2	6.00	-8	
E	9.90	10.39	
E4	7.30	-	
е	2.54BSC		
G	1.25	1.50	
H2	- Re-	1.31	
L	13.34	14.10	
L1	3.30	4.06	
L3	0.95	1.15	



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID =250 μ A	100			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; ID =250 μ A	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =75A			7.0	mΩ
lgss	Gate-Source Leakage Current	V <sub>GS</sub> =±20V			±0.2	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =100V; V <sub>GS</sub> = 0V			20	μА
V <sub>SD</sub>	Diode forward voltage	Is=75A, V <sub>GS</sub> = 0 V			1.3	V

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